## EV301024885US

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicants: James P. BAUKUS, et al. ) Re: Preliminary Amendment

Serial No.: not yet assigned )
Filed: concurrently herewith ) Group: 2815

Divisional of USSN 09/882,892 ) Examiner: Joseph Nguyen
filed on June 15, 2001 )

For: "A PERMANENTLY ON TRANSISTOR ) Our Ref: B-3948DIV 621654-4

IMPLEMENTED USING A DOUBLE )
POLYSILICON LAYER CMOS PROCESS )
WITH BURIED CONTACT" ) Date: February 26, 2004

## PRELIMINARY AMENDMENT

MAIL STOP PATENT APPLICATION Commissioner for Patents P.O. BOX 1450 Alexandria, VA 22313-1450

## Sir:

The above-identified application is a divisional of pending prior U.S. Patent Application Serial No. 09/882,892 filed on June 15, 2001. This paper is being filed as a Preliminary Amendment to the above-identified Application being filed concurrently herewith. Prior to the examination of the above-identified Application, it is respectfully requested that the amendments presented below be made to the Application.

Amendments to the Specification begin on page 2 of this paper.

Amendments to the Claims begin on page 3 of this paper.

Amendments to the Abstract begin on page 5 of this paper.

Remarks begin on page 6 of this paper.